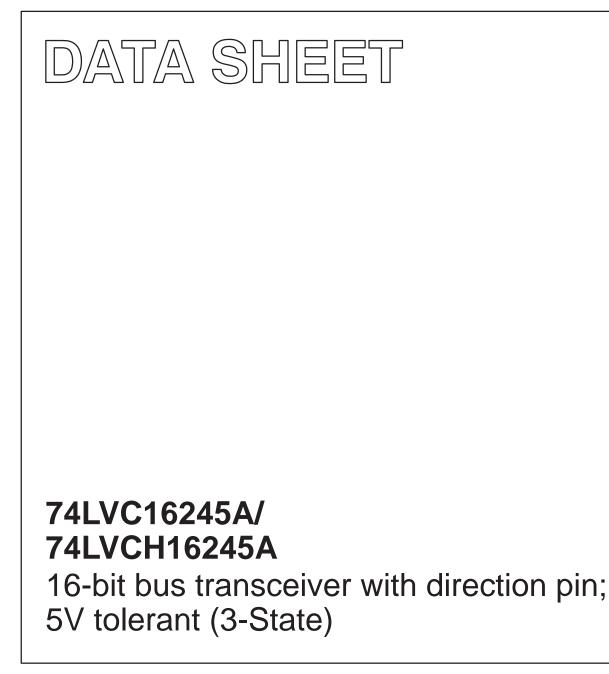
INTEGRATED CIRCUITS



Product specification Supersedes data of 1997 Aug 1 IC24 Data Handbook

1997 Sep 25



Philips Semiconductors



74LVC16245A/ 74LVCH16245A

FEATURES

- 5 volt tolerant inputs/outputs for interfacing with 5V logic
- Wide supply voltage range of 1.2V to 3.6V
- Complies with JEDEC standard no. 8-1A
- CMOS low power consumption
- MULTIBYTETM flow-through standard pin-out architecture
- Low inductance multiple power and ground pins for minimum noise and ground bounce
- Direct interface with TTL levels
- High impedance when V_{CC} = 0
- All data inputs have bus hold (74LVCH16245A only)

DESCRIPTION

The 74LVC(H)16245A is a high-performance, low-power, low-voltage, Si-gate CMOS device, superior to most advanced CMOS compatible TTL families. Inputs can be driven from either 3.3V or 5V devices. In 3-State operation, outputs can handle 5V. These features allow the use of these devices in a mixed 3.3V/5V environment.

The 74LVC(H)16245A is a 16-bit transceiver featuring non-inverting 3-State bus compatible outputs in both send and receive directions. The 74LVC(H)16245A features two output enable (nOE) inputs for easy cascading and two send/receive (nDIR) inputs for direction control. nOE controls the outputs so that the buses are effectively isolated. This device can be used as two 8-bit transceivers or one 16-bit transceiver.

The 74LVCH16245A bus hold data inputs eliminates the need for extreme pull up resistors to hold unused inputs.

PIN CONFIGURATION

1DIR 1	48 10E
1B0 2	47 1A0
1B1 3	46 1A1
GND 4	45 GND
1B2 5	44 1A2
1B3 6	43 1A3
V _{CC1} 7	42 V _{CC2}
1B4 8	41 1A4
1B5 9	40 1A5
GND 10	39 GND
1B6 11	38 1A6
1B7 12	37 1A7
2B0 13	36 2A0
2B1 14	35 2A1
GND 15	34 GND
2B2 16	33 2A2
2B3 17	32 2A3
V _{CC1} 18	31 V _{CC2}
2B4 19	30 2A4
2B5 20	29 2A5
GND 21	28 GND
2B6 22	27 2A6
2B7 23	26 2A7
2DIR 24	25 20E
	SW00198

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	–40°C to +85°C	74LVC16245A DL	VC16245A DL	SOT370-1
48-Pin Plastic TSSOP Type II	-40°C to +85°C	74LVC16245A DGG	VC16245A DGG	SOT362-1
48-Pin Plastic SSOP Type III	–40°C to +85°C	74LVCH16245A DL	VCH16245A DL	SOT370-1
48-Pin Plastic TSSOP Type II	–40°C to +85°C	74LVCH16245A DGG	VCH16245A DGG	SOT362-1

QUICK REFERENCE DATA

GND = 0V; $T_{amb} = 25^{\circ}C$; $t_r = t_f \le 2.5ns$

SYMBOL	PARAMETER	CONDITIONS	TYPICAL	UNIT
t _{PHL} /t _{PLH}	Propagation delay An to Bn; Bn to An	$C_{L} = 50 pF$ $V_{CC} = 3.3V$	3.0	ns
Cl	Input capacitance		5.0	pF
C _{I/O}	Input/output capacitance		10	pF
C _{PD}	Power dissipation capacitance per buffer	$V_{I} = GND$ to V_{CC}^{1}	30	pF

NOTES:

 C_{PD} is used to determine the dynamic power dissipation (P_D in μ W): 1.

 Σ (C_L × V_{CC}² × f_o) = sum of the outputs.

 $P_D = C_{PD} \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o)$ where:

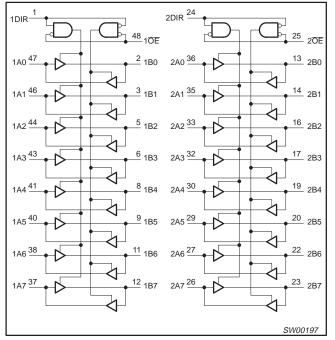
 $f_i = \text{input frequency in MHz; } C_L = \text{output load capacity in pF;} \\ f_o = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V;}$

74LVC16245A/ 74LVCH16245A

PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1	1DIR	Direction control
2, 3, 5, 6, 8, 9, 11, 12	1B0 to 1B7	Data inputs/outputs
4, 10, 15, 21, 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage
13, 14, 16, 17, 19, 20, 22, 23	2B0 to 2B7	Data inputs/outputs
24	2DIR	Direction control
25	2 0E	Output enable input (active LOW)
36, 35, 33, 32, 30, 29, 27, 26	2A0 to 2A7	Data inputs/outputs
47, 46, 44, 43, 41, 40, 38, 37	1A0 to 1A7	Data inputs/outputs
48	1 0E	Output enable input (active LOW)

LOGIC SYMBOL



FUNCTION TABLE

INP	JTS	INPUTS/	OUTPUT
nOE	nDIR	nAn	nBn
L	L	A = B	inputs
L	Н	inputs	B = A
Н	Х	Z	Z

H = HIGH voltage level

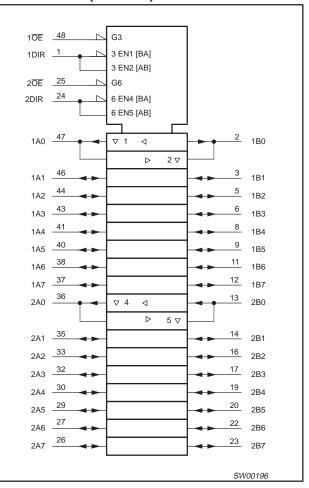
L = LOW voltage level

X = don't care

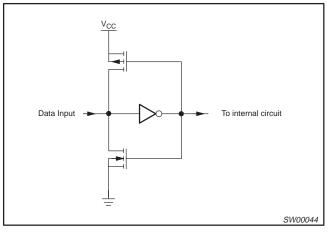
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Z = high impedance OFF-state

LOGIC SYMBOL (IEEE/IEC)



BUS HOLD CIRCUIT



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RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	LIM	UNIT	
STMBOL	FARAMETER	CONDITIONS	MIN.	MAX.	
V _{CC}	DC supply voltage (for max. speed performance)		2.7	3.6	V
V _{CC}	DC supply voltage (for low-voltage applications)		1.2	3.6	V
VI	DC Input voltage range		0	5.5	V
Vo	DC output voltage range; output HIGH or LOW state		0	V _{CC}	V
Vo	DC output voltage range; output 3-State		0	5.5	V
T _{amb}	Operating ambient temperature range in free air		-40	+85	°C
t _r , t _f	Input rise and fall times	$V_{CC} = 1.2 \text{ to } 2.7 \text{V}$ $V_{CC} = 2.7 \text{ to } 3.6 \text{V}$	0 0	20 10	ns/V

ABSOLUTE MAXIMUM RATINGS¹

In accordance with the Absolute Maximum Rating System (IEC 134) Voltages are referenced to GND (ground = 0V)

SYMBOL	PARAMETER	CONDITIONS	LIN	NITS	UNIT
STWBUL		CONDITIONS	MIN	MAX	
V _{CC}	DC supply voltage		-0.5	+6.5	V
I _{IK}	DC input diode current	V ₁ < 0	_	-50	mA
VI	DC input voltage	Note 2	-0.5	+6.5	V
I _{ОК}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	_	±50	mA
Vo	DC output voltage; output HIGH or LOW state	Note 2	-0.5	V _{CC} + 0.5	V
Vo	DC output voltage; output 3-State	Note 2	-0.5	6.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	_	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		_	±100	mA
T _{stg}	Storage temperature range		-65	+150	°C
	Power dissipation per package				
Ptot	– SO package	Above +70°C derate linearly 8mW/K		500	mW
	 SSOP and TSSOP package 	Above +60°C derate linearly 5.5mW/K		500	

NOTES:

 Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

2. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.

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DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltages are referenced to GND (ground = 0V)

			L	IMITS			
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = -40°C to +85°C				
			MIN TYP ¹ MAX		MAX	1	
M		$V_{CC} = 1.2V$	V _{CC}			V	
V _{IH}	HIGH level Input voltage	V _{CC} = 2.7 to 3.6V	2.0			`	
V	LOW level Input voltage	$V_{CC} = 1.2V$			GND	V	
V_{IL}	Low level input voltage	V _{CC} = 2.7 to 3.6V			0.8	ľ	
		$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -12mA$	V _{CC} -0.5				
N/		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -100 \mu A$	V _{CC} -0.2	V _{CC}			
V _{OH}	HIGH level output voltage	$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -18\text{mA}$	V _{CC} -0.6			V	
		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = -24\text{mA}$	V _{CC} -0.8			1	
	V _{OL} LOW level output voltage	$V_{CC} = 2.7V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 12mA$			0.40	v	
V _{OL}		$V_{CC} = 3.0V; V_I = V_{IH} \text{ or } V_{IL}; I_O = 100 \mu A$			0.20		
		V_{CC} = 3.0V; V_I = V_{IH} or V_{IL} ; I_O = 24mA			0.55	1	
ł _l	Input leakage current	$V_{CC} = 3.6V; V_1 = 5.5V \text{ or GND}$		±0.1	±5	μA	
I _{OZ}	3-State output OFF-state current ⁷	$V_{CC} = 3.6V; V_I = V_{IH} \text{ or } V_{IL}; V_O = 5.5V \text{ or GND}$		0.1	±5	μA	
I _{off}	Power off leakage supply	$V_{CC} = 0.0V; V_1 \text{ or } V_0 = 5.5V$		0.1	±10	μA	
I _{CC}	Quiescent supply current	$V_{CC} = 3.6V; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0$		0.1	20	μA	
ΔI_{CC}	Additional quiescent supply current per input pin	$V_{CC} = 2.7V$ to 3.6V; $V_I = V_{CC} - 0.6V$; $I_O = 0$		5	500	μΑ	
I _{BHL}	Bus hold LOW sustaining current	$V_{CC} = 3.0V; V_1 = 0.8V^{2, 3, 4}$	75			μA	
I _{BHH}	Bus hold HIGH sustaining current	$V_{CC} = 3.0V; V_1 = 2.0V^{2, 3, 4}$	-75			μA	
I _{BHLO}	Bus hold LOW overdrive current	V _{CC} = 3.6V ^{2, 3, 5}	500			μA	
I _{BHHO}	Bus hold HIGH overdrive current	$V_{\rm CC} = 3.6 V^{2, 3, 5}$	-500			μA	

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^{\circ}C$. 2. Valid for data inputs of bus hold parts (LVCH16-A) only.

3. For data inputs only, control inputs do not have a bus hold circuit.

The specified sustaining current at the data input holds the input below the specified V₁ level. 4.

5. The specified overdrive current at the data input forces the data input to the opposite logic input state.

6. For bus hold parts, the bus hold circuit is switched off when V_i exceeds V_{CC} allowing 5.5V on the input terminal.

7. For I/O ports the parameter IOZ includes the input leakage current.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

						LIMITS			
SYMBOL	PARAMETER	WAVEFORM	V _{CC}	= 3.3V ±	0.3V	V _{CC} =	: 2.7V	V _{CC} = 1.2V	UNIT
			MIN	TYP ¹	MAX	MIN	MAX	TYP	
t _{PHL} t _{PLH}	Propagation delay nAn to nBn; nBn to nAn	1	1.5	3	4.5	1.5	5.5	13	ns
^t PZH ^t PZL	3-State output enable time nOE to nAn; nOE to nBn	2, 3	1.5	4	6.1	1.5	7.1	15	ns
t _{PHZ} t _{PLZ}	3-State output disable time nOE to nAn; nOE to nBn	2, 3	1.5	4	5.6	1.5	6.6	11	ns

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25° C.

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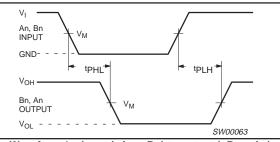
16-bit bus transceiver with direction pin; 5V tolerant (3-State)

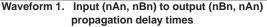
74LVC16245A/ 74LVCH16245A

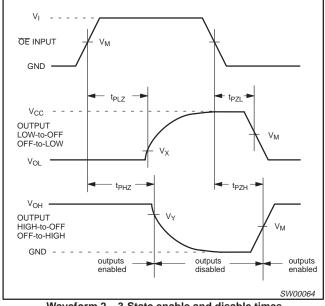
AC WAVEFORMS

 V_M = 1.5V at $V_{CC} \ge$ 2.7V; V_M = 0.5 V_{CC} at $V_{CC} <$ 2.7V. V_{OL} and V_{OH} are the typical output voltage drop that occur with the output load.

 V_X = V_{OL} + 0.3V at V_{CC} \geq 2.7V; V_X = V_{OL} + 0.1 V_{CC} at V_{CC} < 2.7V V_Y = V_{OH} –0.3V at V_{CC} \geq 2.7V; V_Y = V_{OH} –0.1 V_{CC} at V_{CC} < 2.7V

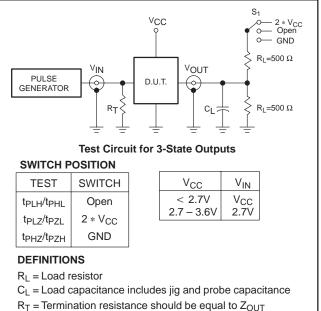








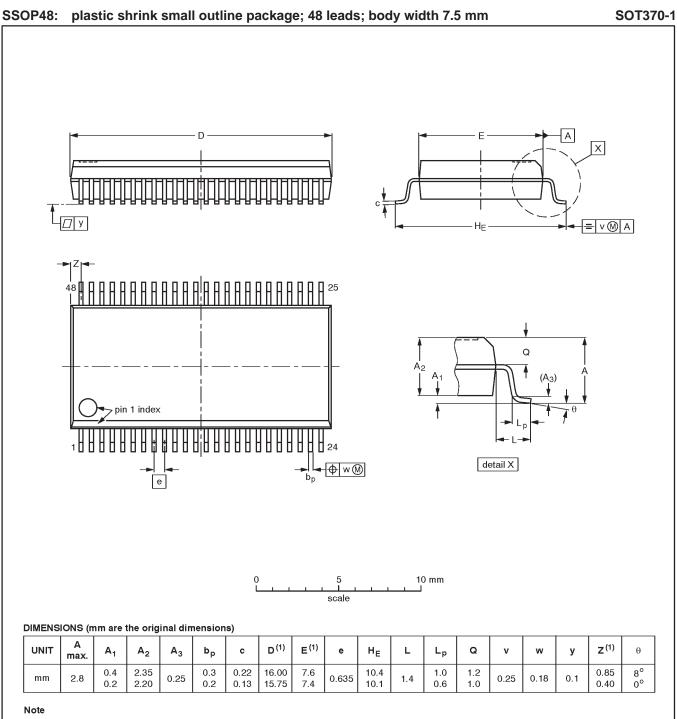
TEST CIRCUIT



 R_T = Termination resistance should be equal to Z_{OU} of pulse generators.

Waveform 3. Load circuitry for switching times

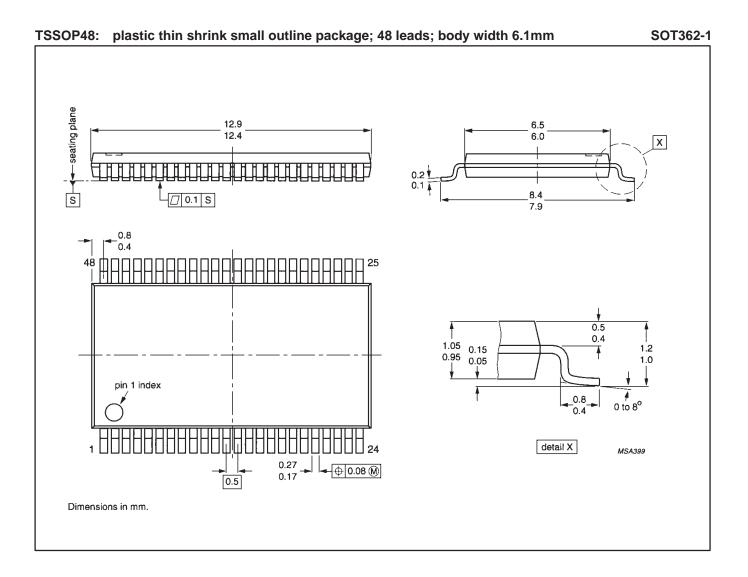
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1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	1550E DATE
SOT370-1		MO-118AA				93-11-02 95-02-04

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NOTES

74LVC16245A/ 74LVCH16245A

	DEFINITIONS				
Data Sheet Identification Product Status		Definition			
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.			
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